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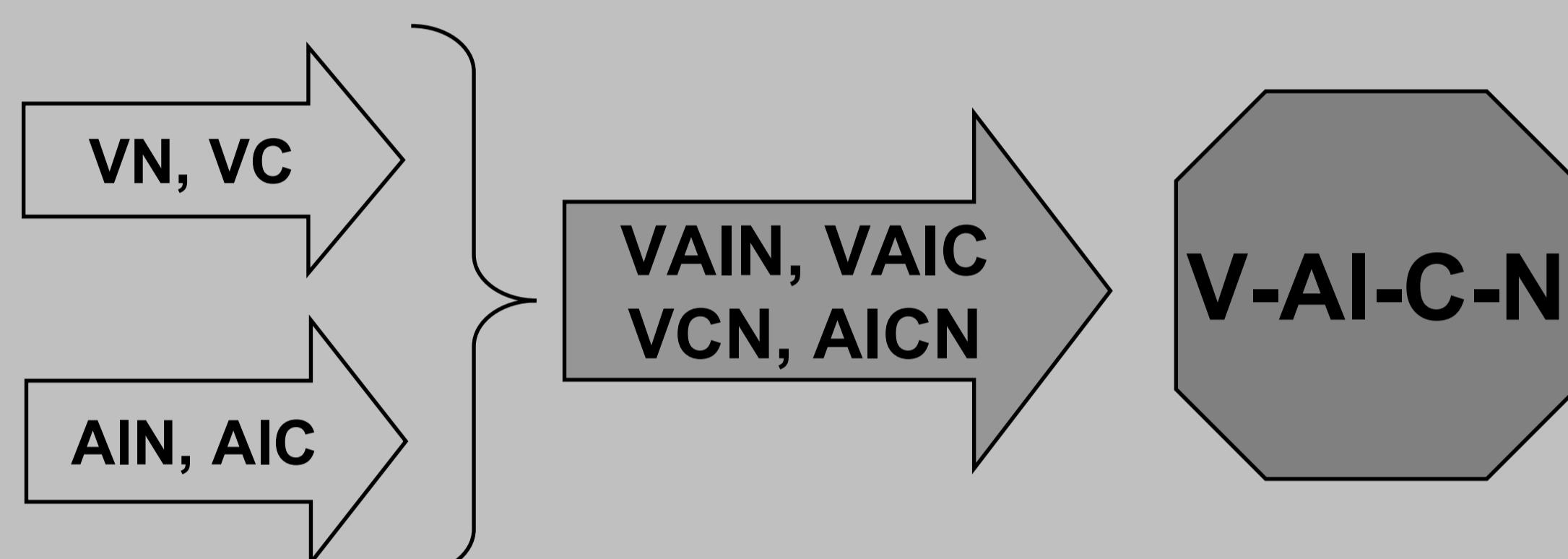
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Deposition and characterization of hard coatings in the material system V-Al-N by reactive magnetron-sputtering

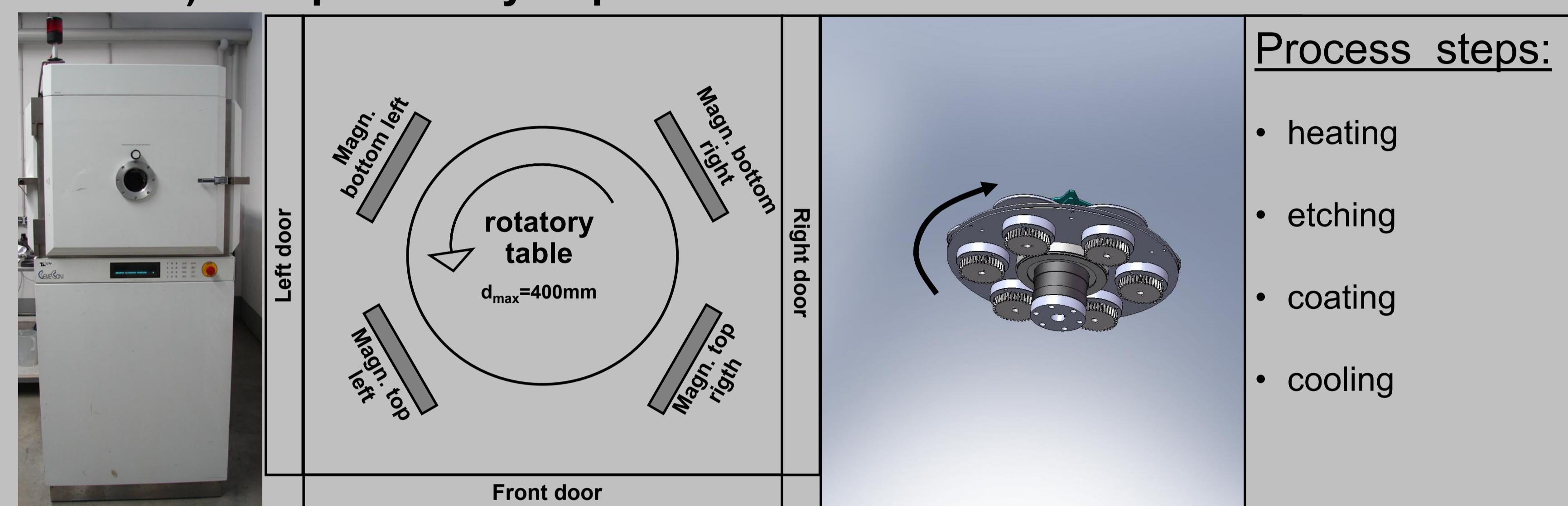
Aim of the work: deposition of new coatings in the material system V-Al-N on industrial plants, to achieve metastable nanostructured hard layers through systematical variation of deposition parameters as power density, plasma pressure and variation of the partial pressure of process-gases (Ar:N₂)

General approach:

- binary coatings: VN, VC (planned), AlN, (AlC)
- ternary coatings VAIN, VCN, VAIC, AICN
- V-Al-C-N-coatings



Realisation: dc magnetron-sputter industrial deposition system (CemeCon CC800/8) with possibility to process in rf mode



- Process steps:**
- heating
 - etching
 - coating
 - cooling

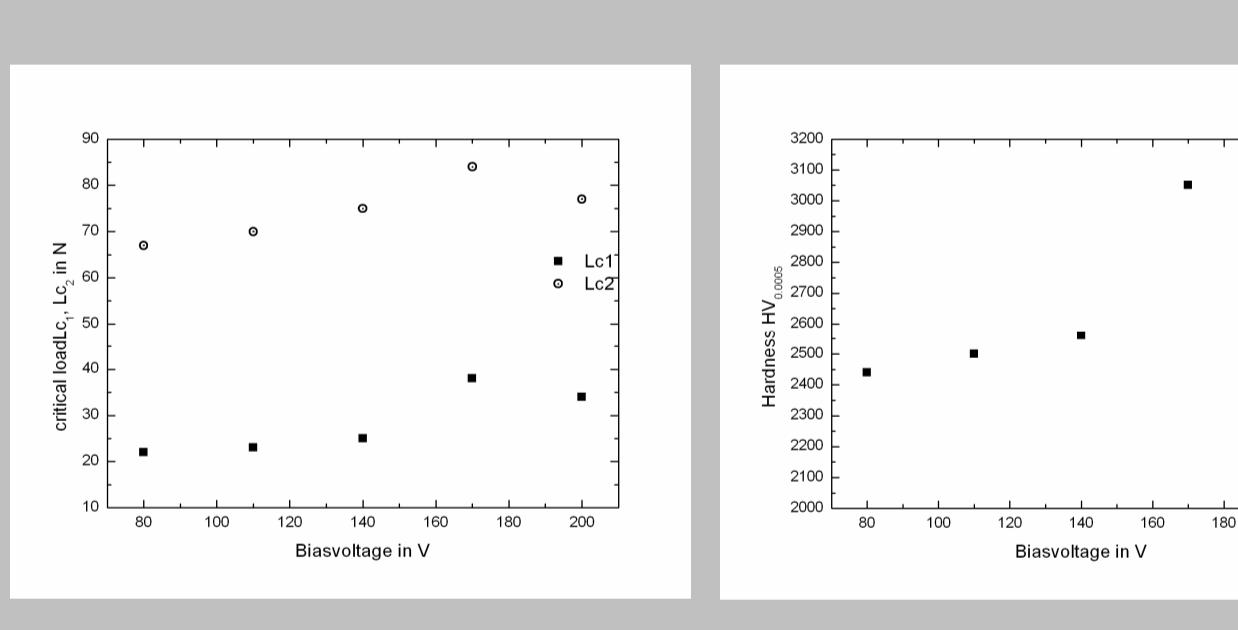
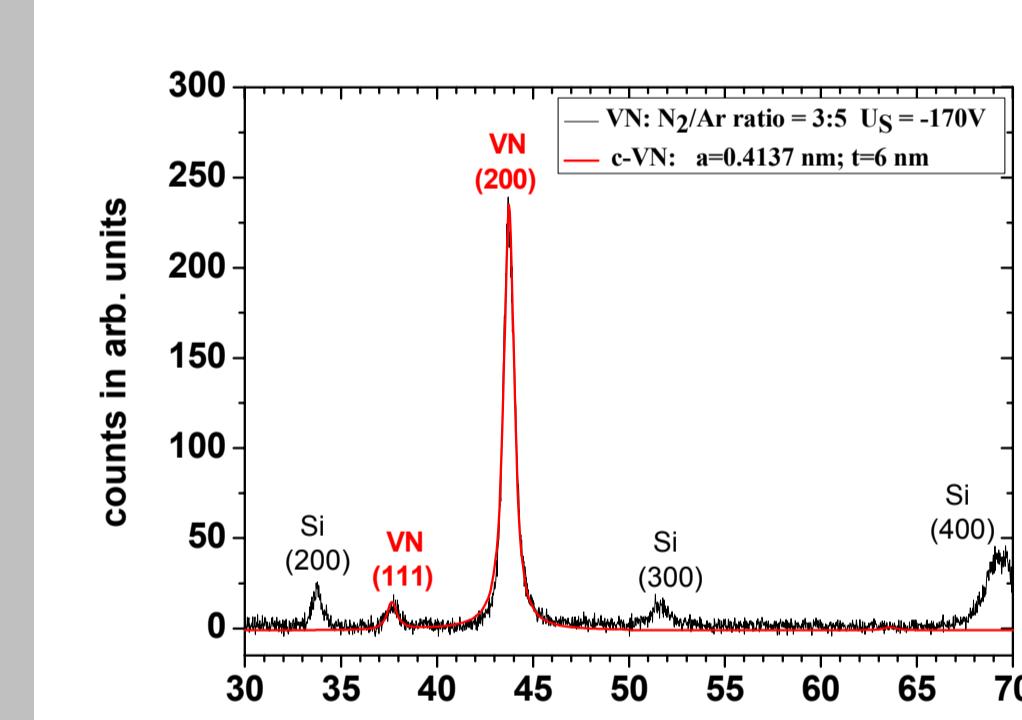
Flexible controlling: variation of many parameters in each process step possible

First results in dc-magnetron-sputtered binary VN-, AlN- and VAIN-coatings:

VN-coatings:

Varied coating parameters Ar:N₂ ratio and U_{bias}

Ar:N ₂ -ratio	U _{bias} in V	L _{c1}	HV _{0.005}
250/150	-200	34	2830
250/150	-170	38	3050
250/150	-140	25	2560
250/150	-110	23	2500
250/150	-80	22	2440



XRD-spectra: nanocrystalline structure of layer with best mechanical properties

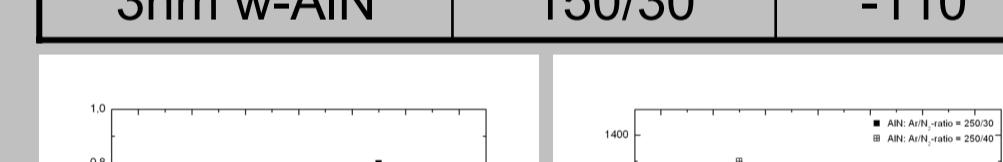
nc-VN	N in at%	V in at%
6nm	43,18	56,36

Composition measured by means of EPMA-method

AlN-coatings:

Coating parameters (bias voltage variation)

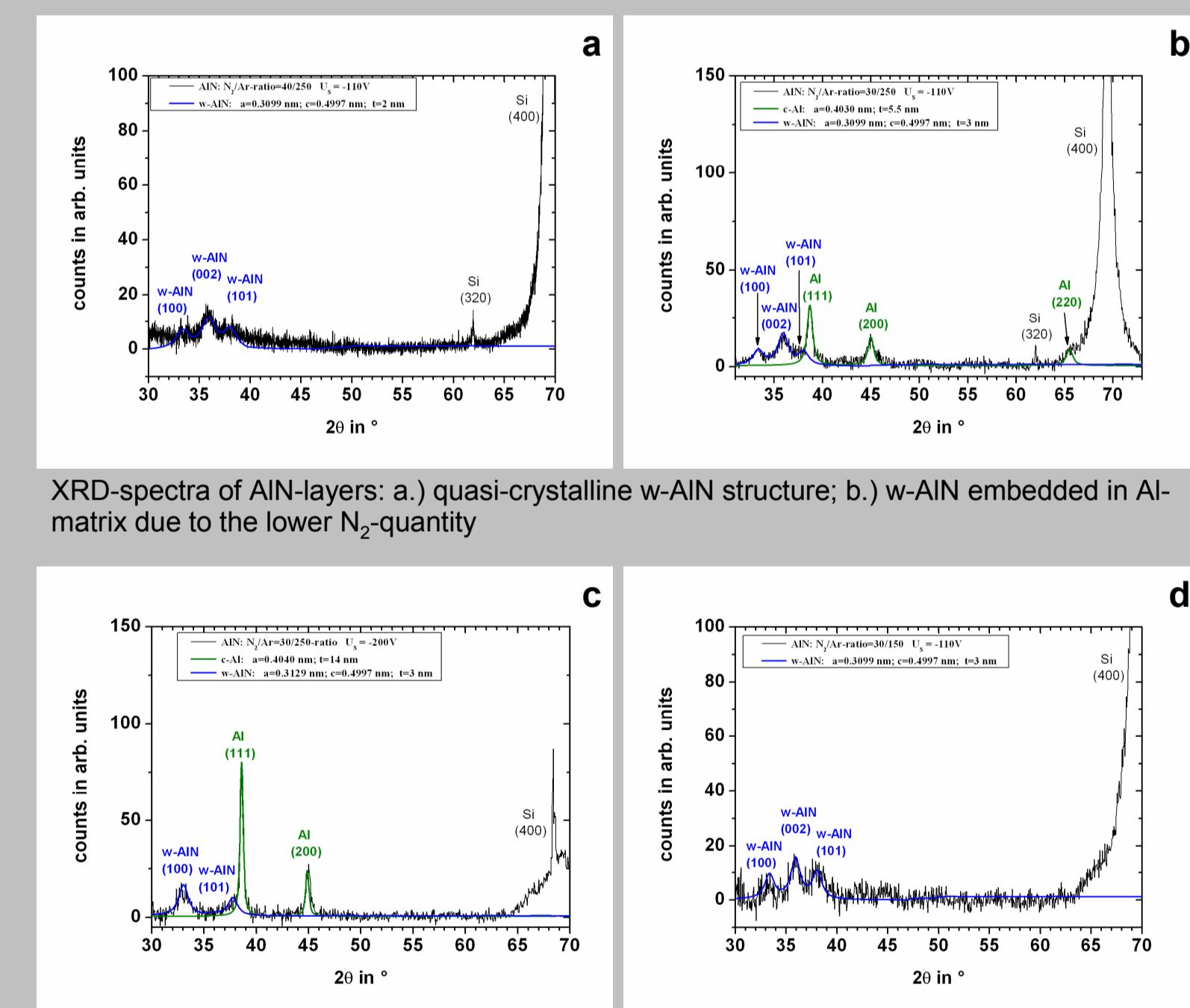
AlN (or Al+N)	Ar:N ₂ -ratio	U _{bias} in V
2nm w-AlN	250/40	-110
3nm w-AlN+Al	250/30	-110
3nm w-AlN+Al	250/30	-200
3nm w-AlN	150/30	-110



XRD-spectra of AlN-layers: a.) quasi-crystalline w-AlN structure; b.) w-AlN embedded in Al-matrix due to the lower N₂-quantity

AlN (or Al+N)	N in at%	Al in at%
2nm	38,07	60,68
3nm	30,08	68,78
3nm	43,54	55,37
3nm	17,07	75,22

Composition measured by means of EPMA-method

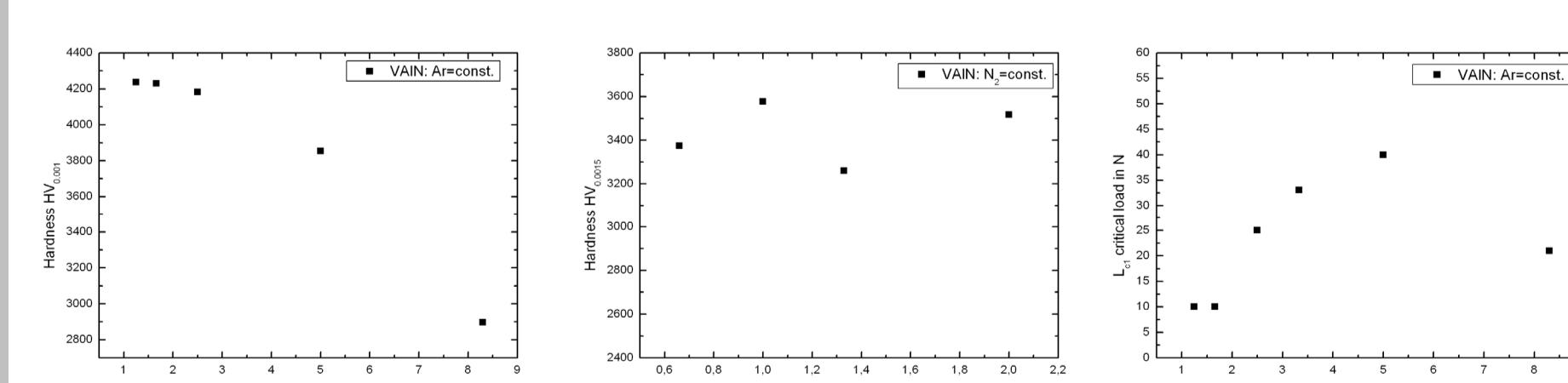
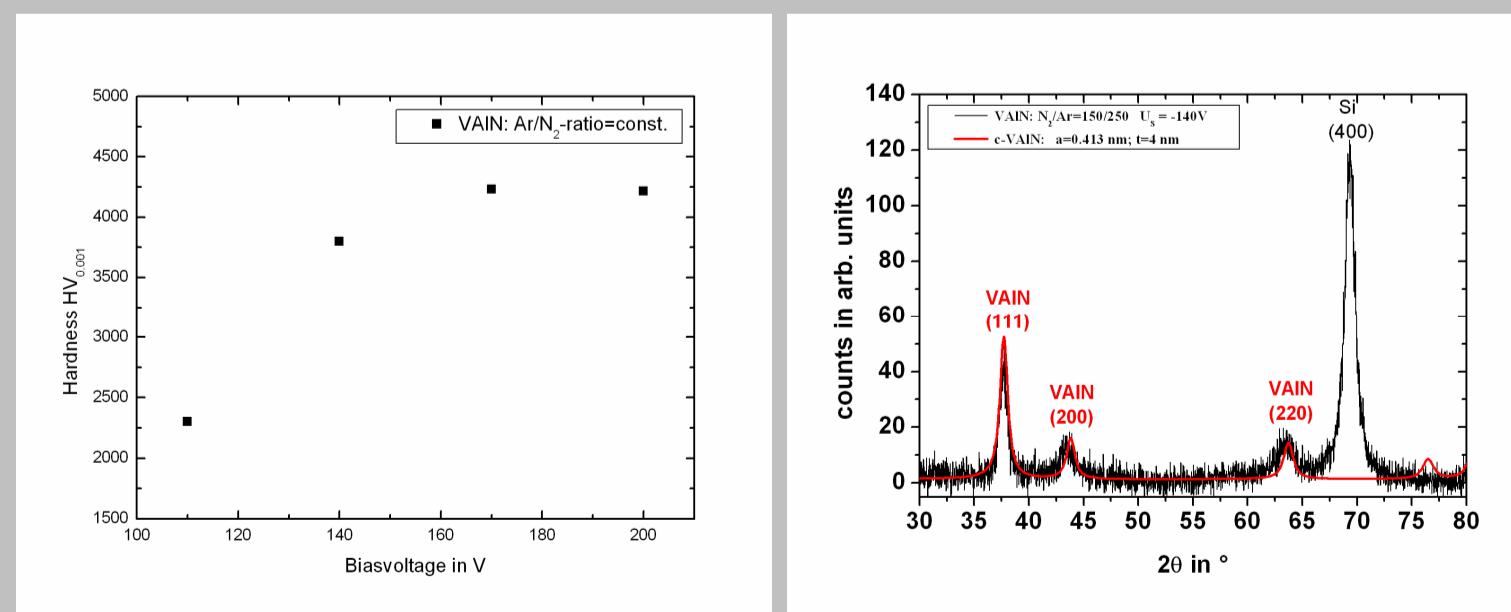


XRD-spectra of AlN-layers: c.) w-AlN embedded in Al-matrix; d.) w-AlN structure

VAIN-coatings:

Varied coating parameters are pressure (Ar:N₂ ratio, 1.case Ar quantity=const., 2.case N₂=const.) and U_{bias}

Ar:N ₂ -ratio 1.case	Ar:N ₂ -ratio 2.case	U _{bias} in V at Ar:N ₂ =250/150
250/30	300/150	-80
250/50	250/150	-110
250/75	200/150	-140
250/100	150/150	-170
250/150	100/150	-200
250/200		



Results and Outlook:

Results VN:

- VN-coating nanocrystalline
- average crystallite size ~6nm
- near-stoichiometric
- friction coefficient ~0.7

Results AlN:

- difficult processing by both dc and rf magnetron sputtering
- average crystallite size ~3nm
- w-AlN-structure, near-amorph
- friction coefficient ~0.7
- variation of Ar:N₂-ratio has no influence on friction coefficient

Results VAIN:

- VAIN-coating nanocrystalline
- average crystallite size ~4nm
- near-stoichiometric
- friction coefficient ~0.7
- probably mixture of VN and AlN
- mechanical properties advantageous

First experiments in the material system V-Al-C-N show:

- C-content in V-layers has an impact on friction coefficient (adjustable from 0.2-0.5)
- combination of hard, metastable materials with a low friction coefficient on an industrial machine feasible
- first steps to understand the quaternary V-Al-C-N system by studying binary VN-, AlN- and ternary VAIN-systems are done
- next steps: fabrication of VC-, VAIC- and AlCN-layer-systems